# LN9710, LN9710P

# Medium Power Laser Diodes

### ■ Outline

LN9710 and LN9710P are visible GaAlAs laser diodes enabling stable single continuous oscillation of transverse mode in room temperature. Two polarities are available for medium power and possible to operate continuously in high temperature. APC (Automatic Power Control) operation is enabled due to built-in PIN photodiode used for light power monitor. They can be widely applied for light source of laser beam printer, facsimile, optical disc memory drive and optical communication apparatus.

### **■** Features

- · Low threshold current
- Stable single transverse mode oscillation
- With monitor PIN photodiode for radiant output control
- Radiant can be continuously varied up to 10mW
- Direct modulation available
- Visible oscillation wavelength
- Long lifetime, high reliability

Item		Symbol	Value	Unit	
Optical Power Output		Po	10	mW	
Reverse Voltage	Laser	V <sub>R</sub>	2	W C	
Reverse voltage	PIN	V <sub>R</sub> (PIN)	30	V	
Power Dissipation		P <sub>d</sub> (PIN)	60	mW	
Operating Temper	rature	Topr	-10~+60	%°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°	
Storage Tempera	ture	T <sub>stg</sub>	-40~+85	) 5°	

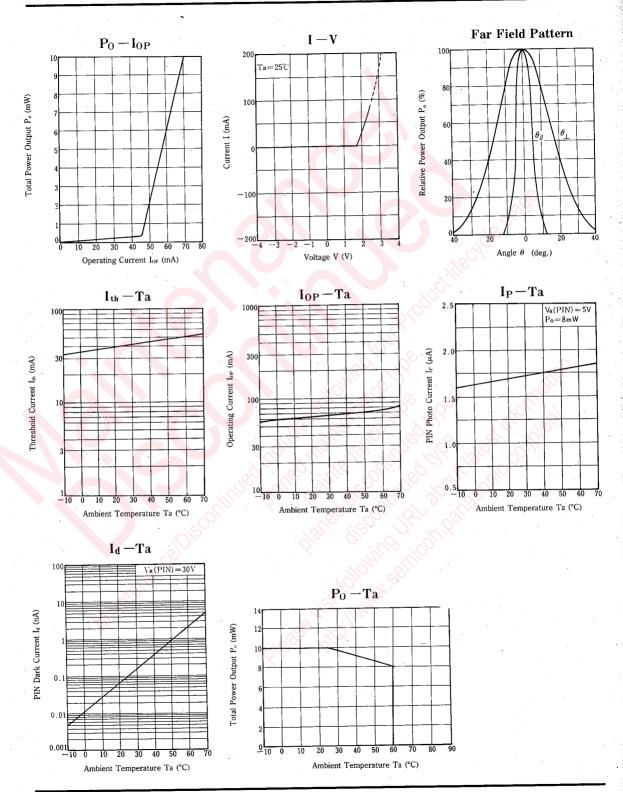
# ■ Absolute Maximum Ratings (Ta=25°C)

## ■ Electro-Optical Characteristics (Ta=25°C)

Item		Symbol	Condition	min.	typ.	max.	Unit
Threshold Current		I <sub>th</sub>	CW .	25	45	70	mA
Operating Current		IOP	$P_0 = 8mW$	45	65	90	mA
Operating Voltage		Vop	$P_0 = 8mW$		2	3	V
Wavelength		$\lambda_{\mathbf{L}}$	$P_0 = 8mW$	775	790	810	nm
Radiation Half	Horizontal Direction	θ"*	$P_0 = 8mW$	9	10	16	deg
Angle	Vertical Direction	$ heta_{\!\scriptscriptstyle \perp}$ *	$P_0 = 8mW$	22	35	48	deg
Differential Efficiency		η	$7 \mathrm{mW}/(\mathrm{I}_{(8 \mathrm{mW})} - \mathrm{I}_{(6 \mathrm{mW})})$	0.1	0.45	0.8	mW/mA
PIN Dark Current		$I_d$	$V_R(PIN) = 30 V$	7 1		0.1	μA
PIN Photo Current		I <sub>P</sub>	$P_0 = 8mW$ , $V_R(PIN) = 5V$	0.5	1.6	2.7	mA
Emission Point	X Direction	$\theta_{\rm X}$	$P_0 = 8mW$			±2	deg.
Angle Accuracy	Y Direction	$\theta_{Y}$	$P_0 = 8mW$			±3	deg.
Oscillation Mode		Single trans	verse mode				<u> </u>

 $<sup>\</sup>theta_{\text{N}}$  and  $\theta_{\text{L}}$  are measured from the optical axis to the half power point.

				Unit: mm
i	• • • • • • • • • • • • • • • • • • • •	1.0		Omin Bottom View
	 \$ 2.45±0.07	\$9 \$6. \$5. 5max.	45 45 1 1 1 1 1 1 1 1	PIN (Photo-diode) (Laser Diode)
	3	-∲0.45	8.0	(a)
4	0	LN9710 (a) Laser Cathode	LN9710P (b) Laser Anode	(PIN (Laser)
	2	Laser Anode PIN Photo- diode Cathode	Common Cathode	(b)
7	3		otodiode ode	, 10°



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